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BCR5FM-14LB

700V - 5A - Triac

R07DS0957EJ0100 Rev.1.00 Oct. 1, 2017

Medium Power Use

Features

• I_{T (RMS)}: 5 A

• $V_{DRM} : 800 \text{ V (Tj} = 125^{\circ}\text{C)}$

• Tj: 150°C

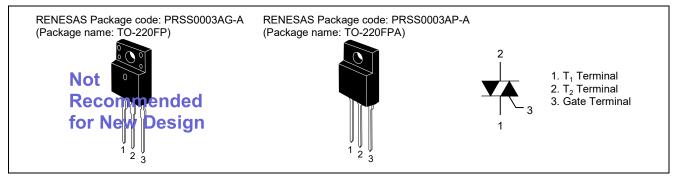
• I_{FGTI}, I_{RGTI}, I_{RGT III}: 30 mA

Insulated Type

• Planar Passivation Type

• Viso: 2000 V

Outline



Application

Power supply, motor control, heater control, solenoid control, and other general purpose AC control applications.

Maximum Ratings

Parameter	Symbol	Voltage class	Unit	Conditions	
		14			
Repetitive peak off-state voltage ^{Note1}	V_{DRM}	800	V	Tj = 125°C	
		700	V	Tj = 150°C	
Non-repetitive peak off-state voltage ^{Note1}	V_{DSM}	840	V		

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I _{T (RMS)}	5	Α	Commercial frequency, sine full wave
				360°conduction, Tc = 113°C
Surge on-state current	I _{TSM}	50	Α	60 Hz sinewave 1 full cycle, peak value,
				non-repetitive
I ² t for fusion	l ² t	10.4	A ² s	Value corresponding to 1 cycle of half wave
				60 Hz, surge on-state current
Peak gate power dissipation	P _{GM}	3	W	
Average gate power dissipation	P _{G (AV)}	0.3	W	
Peak gate voltage	V_{GM}	10	V	
Peak gate current	I _{GM}	2	Α	
Junction Temperature	Tj	-40 to +150	°C	
Storage temperature	Tstg	-40 to +150	°C	
Isolation voltage Note6	Viso	2000	V	Ta=25°C, AC 1 minute,
				T ₁ • T ₂ • G terminal to case

Notes: 1. Gate open.

Electrical Characteristics

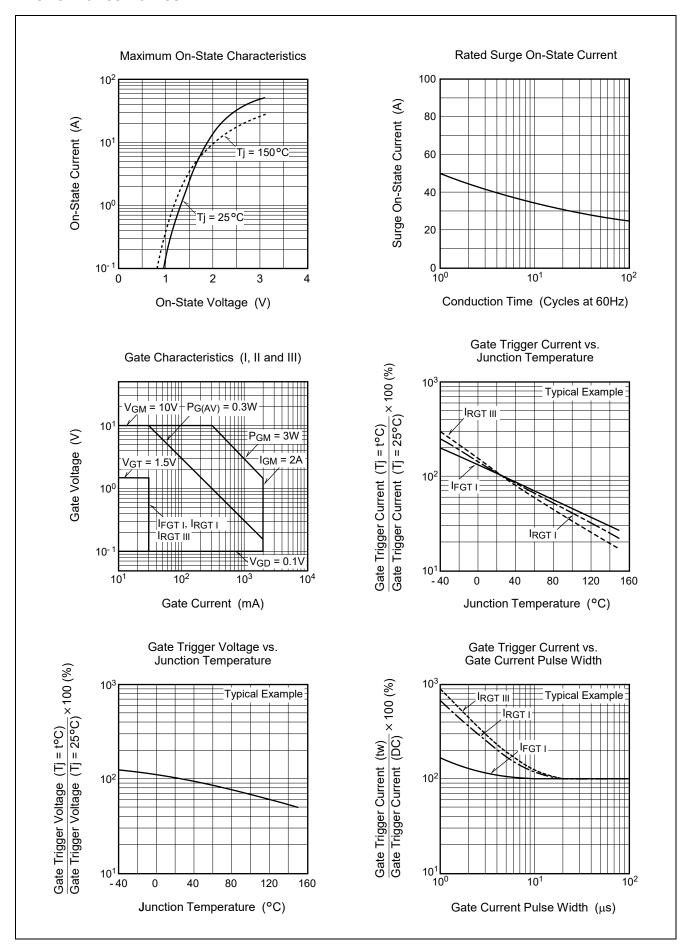
Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak off-state current		I _{DRM}	_	_	2.0	mA	Tj = 150°C, V _{DRM} applied
On-state voltage		V _{TM}	_	_	1.8	V	Tc = 25°C, I _{TM} = 7 A, instantaneous measurement
Gate trigger voltage ^{Note2}	I	V _{FGTI}	_	_	1.5	V	Tj = 25°C, V_D = 6 V, R_L = 6 Ω,
	II	V_{RGTI}	_	_	1.5	V	$R_G = 330 \Omega$
	III	V _{RGTIII}	_	_	1.5	V	
Gate trigger curentNote2	I	I _{FGTI}	_	_	30	mA	$T_{\rm J}$ = 25°C, $V_{\rm D}$ = 6 V, $R_{\rm L}$ = 6 Ω,
	II	I _{RGTI}	_	_	30	mA	$R_G = 330 \Omega$
	III	IRGTIII	_	_	30	mA	
Gate non-trigger voltage		V_{GD}	0.2	_	_	V	Tj = 125°C, V _D = 1/2 V _{DRM}
			0.1	_	_	V	Tj = 150°C, V _D = 1/2 V _{DRM}
Thermal resistance		Rth (j-c)	_	_	4.9	°C/W	Junction to case ^{Note3}
Critical-rate of rise of off-state		(dv/dt)c	5	_	_	V/μs	Tj = 125°C
commutation voltage ^{Note4}			1	_	_	V/μs	Tj = 150°C

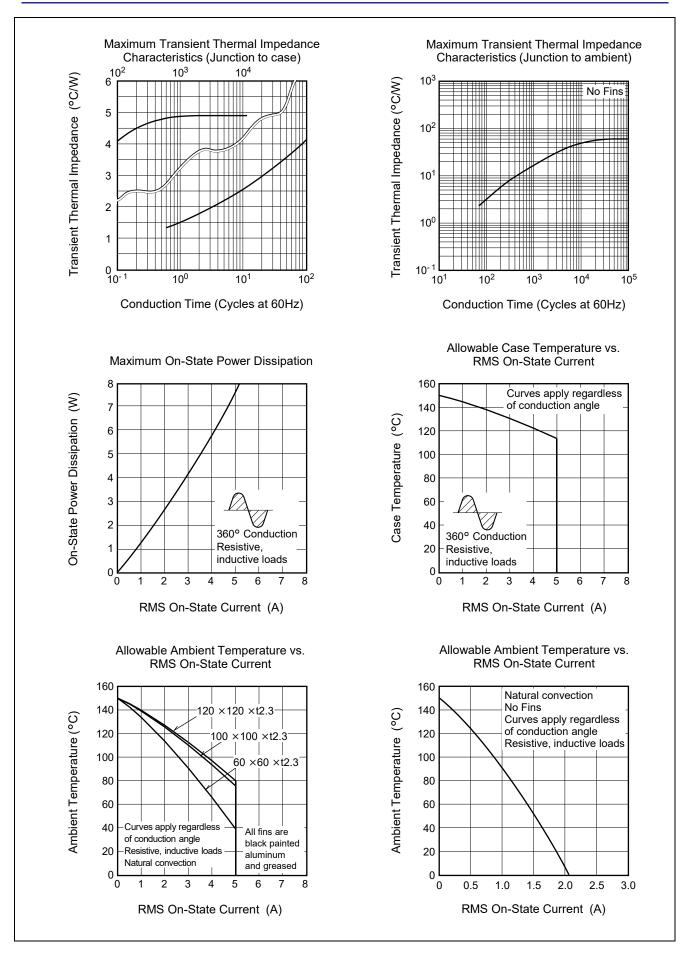
Notes: 2. Measurement using the gate trigger characteristics measurement circuit.

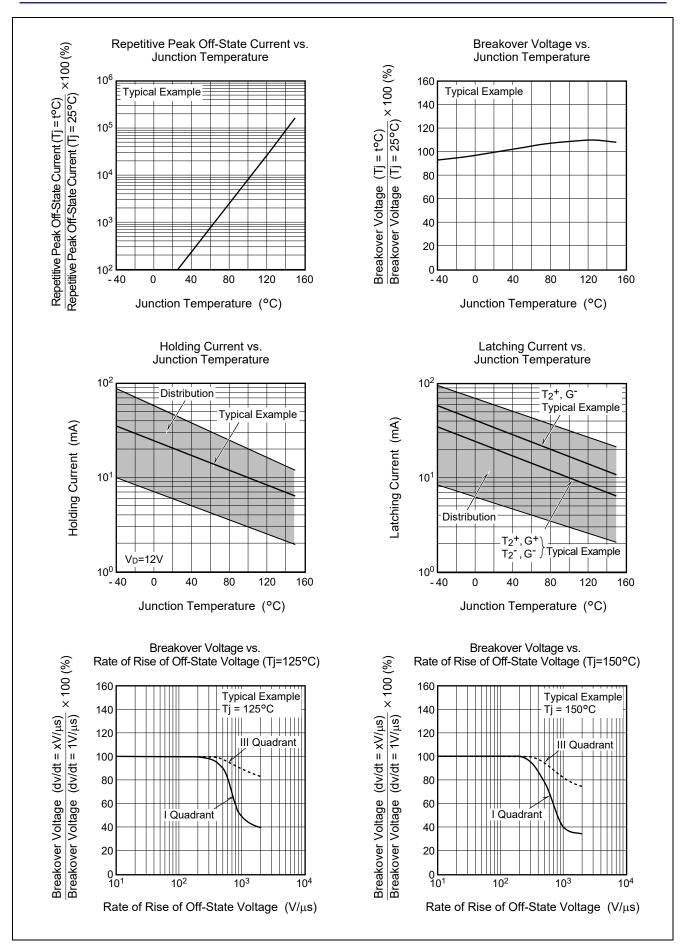
- 3. The contact thermal resistance $R_{th(c-f)}$ in case of greasing is $0.5^{\circ}C$ /W.
- 4. Test conditions of the critical-rate of rise of off-state commutation voltage is shown in the table below.
- 5. Make sure that your finished product containing this device meets your safe isolation requirements. For safety, it's advisable that heatsink is electrically floating.

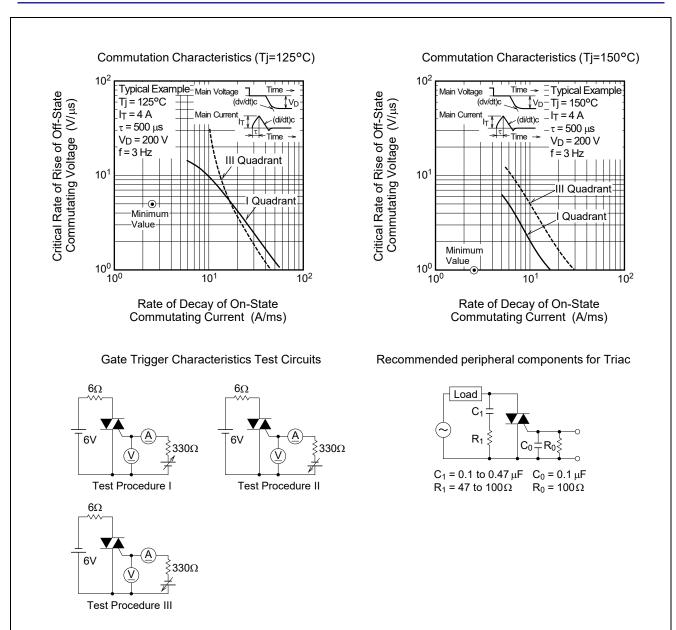
Test conditions	Commutating voltage and current waveforms (inductive load)
 Junction temperature Tj = 125°C/150°C Rate of decay of on-state commutating current (di/dt)c = -2.5 A/ms Peak off-state voltage V_D = 400 V 	Supply Voltage Main Current Main Voltage (di/dt)c Time Main Voltage (dv/dt)c

Performance Curves









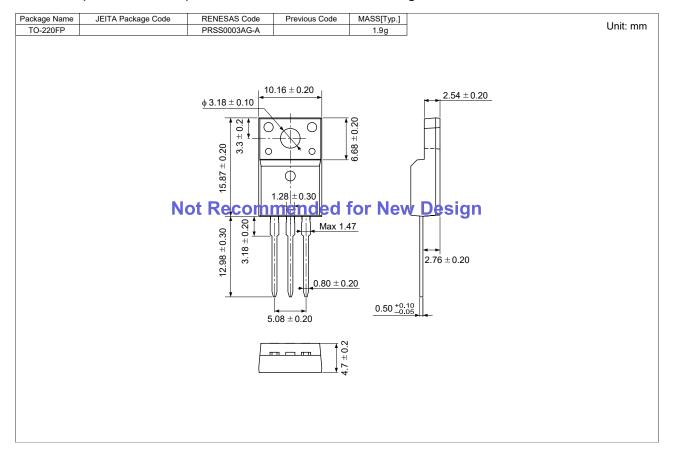
Package Dimensions

TO-220FPA (PRSS0003AP-A)

- PRSS0003AP-A	TO-220FPA	1.65
10.0±0.3		
\$\frac{\cong}{\cong} \frac{\cong}{\cong} \frac	2.7±0.2 0 0 0 0 0 0	Unit: mr

Package Dimensions

TO-220FP (PRSS0003AG-A) <Not Recommended for New Design>



Ordering Information

Orderable Part Number	Package	Quantity Note6	Remark	Status
BCR5FM-14LB#BG0	TO-220FPA	50 pcs./ tube	Straight type	Mass Production
BCR5FM-14LB-□□#BG0	TO-220FPA	50 pcs./ tube	□□:Lead form type	
BCR5FM-14LB#BB0	TO-220FP	50 pcs./ tube	Straight type	Not Recommended for
BCR5FM-14LB-□□#BB0	TO-220FP	50 pcs./ tube	□□:Lead form type	New Design

Notes: 6. Please confirm the specification about the shipping in detail.

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